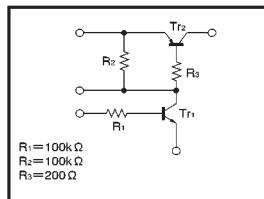


Power management (dual digital transistors)

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FMQ2

Features

- 1) Two digital transistors in a SMT package.
- 2) Up to 500 mA can be driven.
- 3) Low $V_{CE(sat)}$ of drive transistors for low power dissipation.

Circuit schematic**Package, marking, and packaging specifications**

Part No.	FMQ2
Package	SMT5
Marking	Q2
Code	T148
Basic ordering unit (pieces)	3000

Electrical characteristics (Ta = 25°C)

Tr1

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-emitter breakdown voltage	BV _{CBO}	30	—	—	V	I _c =1mA
Collector cutoff current	I _{CBO}	—	—	0.5	μA	V _{ce} =20V
Collector-emitter saturation voltage	V _{CE(sat)}	—	—	0.3	V	I _c =1mA , I _e =0.1mA
DC current transfer ratio	h _{FE}	270	—	—	—	V _{ce} =2V , I _c =1mA
Transition frequency	f _T	—	250	—	MHz	V _{ce} =5V , I _c =−5mA , f=50MHz

*Transition frequency of the device.

Tr2

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-emitter breakdown voltage	BV _{CBO}	−30	—	—	V	I _c =−1mA
Collector cutoff current	I _{CBO}	—	—	−0.5	μA	V _{ce} =−20V
Collector-emitter saturation voltage	V _{CE(sat)}	—	—	−0.3	V	I _c =−100mA , I _e =−10mA
DC current transfer ratio	h _{FE}	120	—	—	—	V _{ce} =−2V , I _c =−100mA
Transition frequency	f _T	—	200	—	MHz	V _{ce} =−5V , I _c =50mA , f=50MHz

*Transition frequency of the device.

Resistor values

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Resistor 1	R ₁	70	100	130	kΩ	—
Resistor 2	R ₂	70	100	130	kΩ	—
Resistor 3	R ₃	140	200	260	Ω	—